

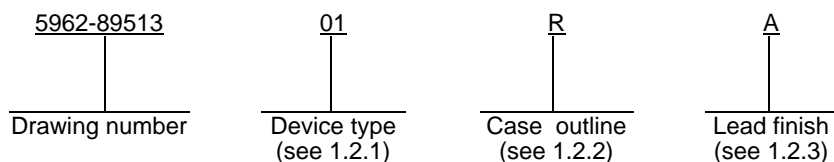
REVISIONS																			
LTR	DESCRIPTION										DATE (YR-MO-DA)				APPROVED				
A	Changes in accordance with NOR 5962-R070-92. - JAK										92-01-13				Monica L. Poelking				
B	Correct title to accurately describe device function. Update boilerplate to MIL-PRF-38535 requirements. Editorial changes throughout. - LTG										06-08-01				Thomas M. Hess				
C	Add footnote 4/ for I _{CC} tests in table I. – jak										10-01-19				Thomas M. Hess				

REV																				
SHEET																				
REV																				
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REV STATUS OF SHEETS				REV		B	B	B	B	B	B	B	B	B	B	B	B	B		
				SHEET		1	2	3	4	5	6	7	8	9	10	11	12			
PMIC N/A				PREPARED BY Monica L. Poelking						DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990 http://www.dscc.dla.mil										
STANDARD MICROCIRCUIT DRAWING THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE AMSC N/A				CHECKED BY Ray Monnin																
				APPROVED BY Michael A. Frye						MICROCIRCUIT, DIGITAL, FAST CMOS, OCTAL-D-REGISTER WITH THREE-STATE OUTPUTS, TTL COMPATIBLE, MONOLITHIC SILICON										
				DRAWING APPROVAL DATE 89-04-07																
				REVISION LEVEL B						SIZE A	CAGE CODE 67268	5962-89513								
						SHEET 1 OF 12														

1. SCOPE

1.1 Scope. This drawing describes device requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A.

1.2 Part or Identifying Number (PIN). The complete PIN is as shown in the following example:



1.2.1 Device type(s). The device type(s) identify the circuit function as follows:

Device type	Generic number	Circuit function
01	54FCT574	Octal D register with three-state outputs, TTL compatible
02	54FCT574A	Octal D register with three-state outputs, TTL compatible

1.2.2 Case outline(s). The case outline(s) are as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	Terminals	Package style
R	GDIP1-T20 or CDIP2-T20	20	Dual-in-line
S	GDFP2-F20 or CDFP3-F20	20	Flat pack
2	CQCC1-N20	20	Square leadless chip carrier

1.2.3 Lead finish. The lead finish is as specified in MIL-PRF-38535, appendix A.

1.3 Absolute maximum ratings. ^{1/}

Supply voltage range (V_{CC})	-0.5 V dc to +7.0 V dc
DC input voltage range (V_{IN})	-0.5 V dc to $V_{CC} + 0.5$ V dc ^{2/}
DC output voltage range (V_{OUT})	-0.5 V dc to $V_{CC} + 0.5$ V dc ^{2/}
DC input diode current (I_{IK})	-20 mA
DC output diode current (I_{OK})	-50 mA
DC output current (I_{OUT})	± 100 mA
Storage temperature range (T_{STG})	-65°C to +150°C
Maximum power dissipation (P_D)	500 mW ^{3/}
Lead temperature (soldering, 10 seconds)	+300°C
Thermal resistance, junction-to-case (θ_{JC})	See MIL-STD-1835
Junction temperature (T_J)	+175°C

1.4 Recommended operating conditions.

Supply voltage range (V_{CC})	+4.5 V dc to +5.5 V dc
Maximum low level input voltage (V_{IL})	0.8 V dc
Minimum high level input voltage (V_{IH})	2.0 V dc
Case operating temperature range (T_C)	-55°C to +125°C
Minimum setup time, Dn to CP, high or low (t_s):	
Device type 01	2.5 ns
Device type 02	2.0 ns
Minimum hold time, Dn to CP, high or low (t_h):	
Device type 01	2.0 ns
Device type 02	1.5 ns
Minimum CP pulse width, high and low (t_w):	
Device type 01	7.0 ns
Device type 02	6.0 ns

^{1/} Unless otherwise specified, all voltages are referenced to ground.

^{2/} For $V_{CC} > 6.5$ V dc, the upper bound is limited to V_{CC} .

^{3/} Must withstand the added P_D due to short circuit test, e.g., I_{OS} .

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2. APPLICABLE DOCUMENTS

2.1 Government specification, standards, and handbooks. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Method Standard Microcircuits.

MIL-STD-1835 - Interface Standard Electronic Component Case Outlines.

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings.

MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at <https://assist.daps.dla.mil/quicksearch/> or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein. Product built to this drawing that is produced by a Qualified Manufacturer Listing (QML) certified and qualified manufacturer or a manufacturer who has been granted transitional certification to MIL-PRF-38535 may be processed as QML product in accordance with the manufacturers approved program plan and qualifying activity approval in accordance with MIL-PRF-38535. This QML flow as documented in the Quality Management (QM) plan may make modifications to the requirements herein. These modifications shall not affect form, fit, or function of the device. These modifications shall not affect the PIN as described herein. A "Q" or "QML" certification mark in accordance with MIL-PRF-38535 is required to identify when the QML flow option is used.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535, appendix A and herein.

3.2.1 Case outlines. The case outlines shall be in accordance with 1.2.2 herein.

3.2.2 Terminal connections. The terminal connections shall be as specified on figure 1.

3.2.3 Truth table. The truth table shall be as specified on figure 2.

3.2.4 Logic diagram. The logic diagram shall be as specified on figure 3.

3.2.5 Switching waveforms and test circuit. The switching waveforms and test circuit shall be as specified on figure 4.

3.3 Electrical performance characteristics. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and shall apply over the full case operating temperature range.

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3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table I.

3.5 Marking. Marking shall be in accordance with MIL-PRF-38535, appendix A. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device.

3.5.1 Certification/compliance mark. A compliance indicator "C" shall be marked on all non-JAN devices built in compliance to MIL-PRF-38535, appendix A. The compliance indicator "C" shall be replaced with a "Q" or "QML" certification mark in accordance with MIL-PRF-38535 to identify when the QML flow option is used.

3.6 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6 herein). The certificate of compliance submitted to DSCC-VA prior to listing as an approved source of supply shall affirm that the manufacturer's product meets the requirements of MIL-PRF-38535, appendix A and the requirements herein.

3.7 Certificate of conformance. A certificate of conformance as required in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.

3.8 Notification of change. Notification of change to DSCC-VA shall be required for any change that affects this drawing.

3.9 Verification and review. DSCC, DSCC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

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TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C V _{CC} = 5.0 V dc ±10% unless otherwise specified		Group A subgroups	Device type	Limits		Unit
						Min	Max	
High level output voltage	V _{OH}	V _{CC} = 4.5 V V _{IL} = 0.8 V V _{IH} = 2.0 V	I _{OH} = -300 μA I _{OH} = -12 mA	1, 2, 3	All	4.3 2.4		V
Low level output voltage	V _{OL}	V _{CC} = 4.5 V V _{IL} = 0.8 V V _{IH} = 2.0 V	I _{OL} = 300 μA I _{OL} = 32 mA	1, 2, 3	All		0.2 0.5	V
Input clamp voltage	V _{IK}	V _{CC} = 4.5 V, I _{IN} = -18 mA		1, 2, 3	All		-1.2	V
High level input current	I _{IH}	V _{CC} = 5.5 V, V _{IN} = 5.5 V		1, 2, 3	All		5.0	μA
Low level input current	I _{IL}	V _{CC} = 5.5 V, V _{IN} = GND		1, 2, 3	All		-5.0	μA
Off-state output current, high	I _{OZH}	V _{CC} = 5.5 V, V _{IN} = 5.5 V		1, 2, 3	All		10	μA
Off-state output current, low	I _{OZL}	V _{CC} = 5.5 V, V _{IN} = GND		1, 2, 3	All		-10	μA
Short circuit output current	I _{OS} 1/	V _{CC} = 5.5 V, V _{OUT} = 0.0 V		1, 2, 3	All	-60		mA
Quiescent power supply current (CMOS inputs)	I _{CCQ} 2/	V _{IN} ≤ 0.2 V or V _{IN} ≥ 5.3 V V _{CC} = 5.5 V, f _I = f _{CP} = 0.0 MHz		1, 2, 3	All		1.5	mA
Quiescent power supply current (TTL inputs)	ΔI _{CC}	V _{CC} = 5.5 V, V _{IN} = 3.4 V		1, 2, 3	All		2.0	mA
Dynamic power supply current	I _{CCD} 3/ 4/	V _{CC} = 5.5 V, \overline{OE} = GND V _{IN} ≤ 0.2 V or V _{IN} ≥ 5.3 V One bit toggling, 50% duty cycle Outputs open C _L = 50 pF		1, 2, 3	All		0.4	mA/ MHz
Total power supply current	I _{CC} 4/ 5/	V _{CC} = 5.5 V f _{CP} = 10 MHz 50% duty cycle Outputs open Eight bits toggling at f _I = 2.5 MHz 50% duty cycle OE = GND	V _{IN} ≤ 0.2 V or V _{IN} ≥ 5.3 V	1, 2, 3	All		5.5	mA
			V _{IN} ≥ 3.4 V or V _{IN} = GND	1, 2, 3	All		6.0	mA
Input capacitance	C _{IN}	See 4.3.1c		4	All		10	pF
Output capacitance	C _{OUT}	See 4.3.1c		4	All		12	pF
Functional tests		See 4.3.1d		7, 8	All			

See footnotes at end of table.

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TABLE I. Electrical performance characteristics – Continued.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C V _{CC} = 5.0 V dc ±10% unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Propagation delay time, CP to On	t _{PLH} , t _{PHL} <u>6/</u>	C _L = 50 pF minimum R _L = 500Ω See figure 4	9, 10, 11	01	2.0	11.0	ns
				02	2.0	7.2	
Propagation delay time, output enable	t _{PZH} , t _{PZL} <u>6/</u>		9, 10, 11	01	1.5	14.0	ns
				02	1.5	7.5	
Propagation delay time, output disable	t _{PHZ} , t _{PLZ} <u>6/</u>		9, 10, 11	01	1.5	8.0	ns
				02	1.5	6.5	

1/ Not more than one output should be shorted at one time, and the duration of the short circuit condition should not exceed one second.

2/ TTL driven input (V_{IN} = 3.4 V); all other inputs at V_{CC} or GND.

3/ This parameter is not directly testable, but is derived for use in total power supply calculations.

4/ For I_{CC} tests, in an ATE environment, the effect of parasitic output capacitive loading from the test environment must be taken into account, as its effect is not intended to be included in the test results. The impact must be characterized and appropriate offset factors must be applied to the test result."

5/ $I_{CC} = I_{CCQ} + (\Delta I_{CC} \times D_H \times N_T) + (I_{CCD}(f_{CP}/2 + f_I \times N_I))$

where: D_H = Duty cycle for TTL inputs high.

N_T = Number of TTL inputs at D_H.

f_I = Input frequency in MHz.

N_I = Number of inputs at f_I.

f_{CP} = Clock frequency for register devices.

6/ The minimum limits are guaranteed, if not tested, to the limits specified in table I.

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Device types	01 and 02
Case outlines	R, S, and 2
Terminal number	Terminal symbol
1	\overline{OE}
2	D0
3	D1
4	D2
5	D3
6	D4
7	D5
8	D6
9	D7
10	GND
11	CP
12	O7
13	O6
14	O5
15	O4
16	O3
17	O2
18	O1
19	O0
20	V _{CC}

FIGURE 1. Terminal connections.

Device types 01 and 02				
Function	Inputs			Outputs
	\overline{OE}	CP	Dn	On
HI-Z	H	L	X	Z
	H	H	X	Z
Load Register	L	↑	L	L
	L	↑	H	H
	H	↑	L	Z
	H	↑	H	Z

H = High voltage level
 L = Low voltage level
 Z = High impedance state
 X = Irrelevant
 ↑ = Low-to-high transition

FIGURE 2. Truth table.

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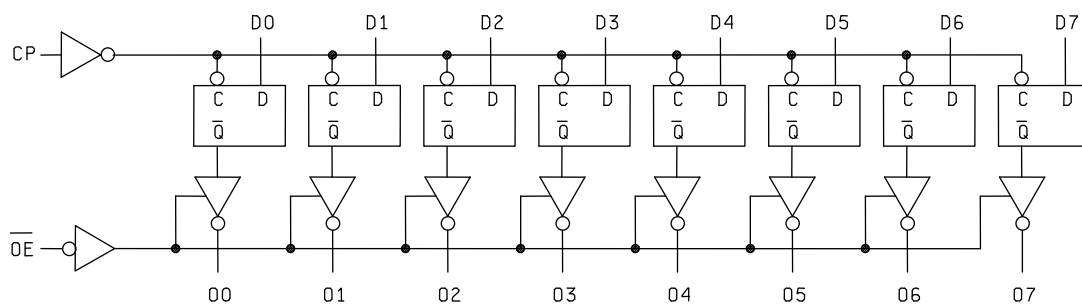


FIGURE 3. Logic diagram.

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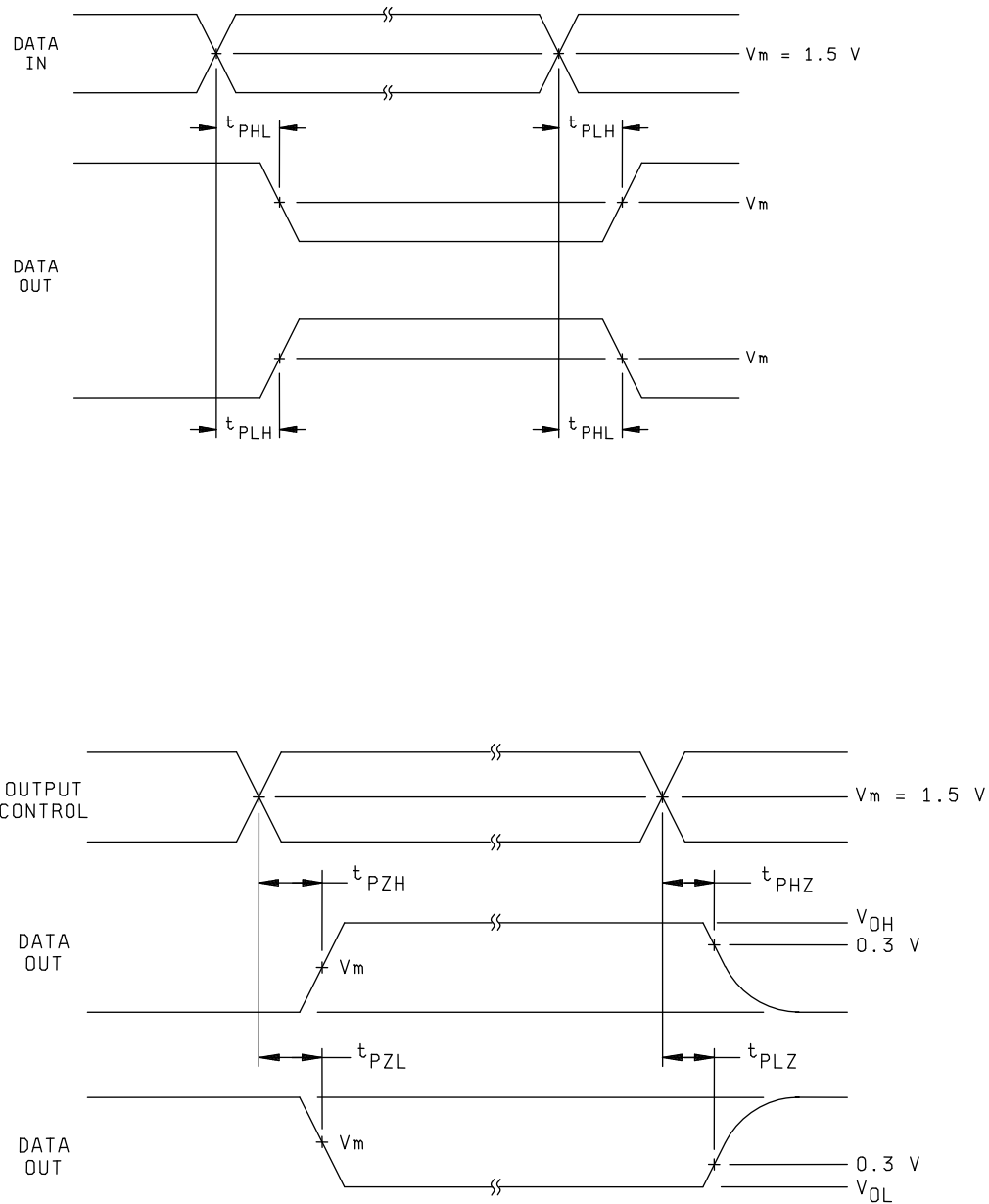


FIGURE 4. Switching waveforms and test circuit.

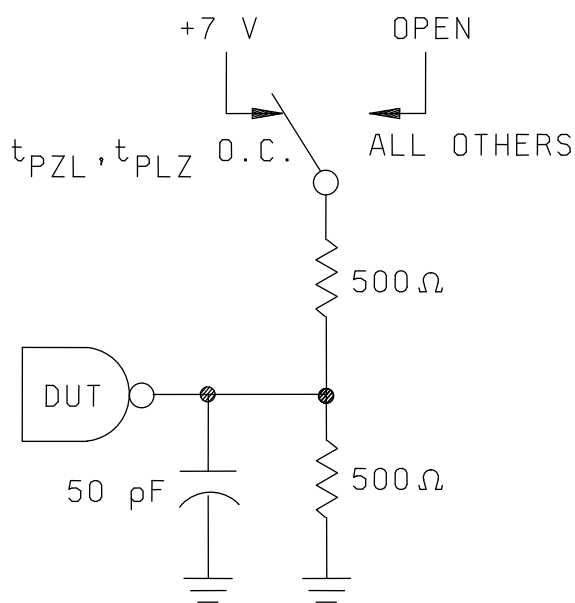
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NOTES:

1. $R_L = 500\Omega$ or equivalent
2. $C_L = 50$ pF or equivalent (includes test jig and probe capacitance).
3. Pulse generator for all pulses: $PRR \leq 1.0$ MHz; $Z_{OUT} \leq 50\Omega$; $t_r \leq 2.5$ ns; $t_f \leq 2.5$ ns

FIGURE 4. Switching waveforms and test circuit – Continued.

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4. VERIFICATION

4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.

4.2 Screening. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:

a. Burn-in test, method 1015 of MIL-STD-883.

(1) Test condition A, B, C, or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.

(2) $T_A = +125^{\circ}\text{C}$, minimum.

b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.

TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups (in accordance with MIL-STD-883, method 5005, table I)
Interim electrical parameters (method 5004)	---
Final electrical test parameters (method 5004)	1*, 2, 3, 7, 8, 9, 10, 11
Group A test requirements (method 5005)	1, 2, 3, 4, 7, 8, 9, 10, 11
Groups C and D end-point electrical parameters (method 5005)	1, 2, 3

* PDA applies to subgroup 1.

4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.

4.3.1 Group A inspection.

a. Tests shall be as specified in table II herein.

b. Subgroups 5 and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.

c. Subgroup 4 (C_{IN} and C_{OUT} measurements) shall be measured only for the initial test and after process or design changes which may affect capacitance. Test all applicable pins on the five devices with zero failures.

d. Subgroups 7 and 8 shall include verification of the truth table as specified on figure 2 herein.

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4.3.2 Groups C and D inspections.

- a. End-point electrical parameters shall be as specified in table II herein.
- b. Steady-state life test conditions, method 1005 of MIL-STD-883.
 - (1) Test condition A, B, C, or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.
 - (2) $T_A = +125^{\circ}\text{C}$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535, appendix A.

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.3 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.

6.4 Record of users. Military and industrial users shall inform Defense Supply Center Columbus (DSCC) when a system application requires configuration control and the applicable SMD. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronics devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0544.

6.5 Comments. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43218-3990 or telephone (614) 692-0547.

6.6 Approved sources of supply. Approved sources of supply are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DSCC-VA.

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STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 10-01-19

Approved sources of supply for SMD 5962-89513 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535. DSCC maintains an online database of all current sources of supply at <http://www.dscclia.mil/Programs/Smcr/>.

Standard microcircuit drawing PIN <u>1/</u>	Vendor CAGE number	Vendor similar PIN <u>2/</u>
5962-89513012A	0C7V7	QP54FCT574LMQB
		IDT54FCT574LB
		54FCT574LMQB
5962-8951301RA	0C7V7	QP54FCT574DMQB
		IDT54FCT574DB
		54FCT574DMQB
5962-8951301SA	0C7V7	QP54FCT574FMQB
		IDT54FCT574EB
		54FCT574FMQB
5962-89513022A	0C7V7	QP54FCT574ALMQB
		IDT54FCT574ALB
5962-8951302RA	0C7V7	QP54FCT574ADMQB
		IDT54FCT574ADB
5962-8951302SA	0C7V7	QP54FCT574AFMQB
		IDT54FCT574AEB

1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed, contact the vendor to determine its availability.

2/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE
number

0C7V7

Vendor name
and address

QP Semiconductor
2945 Oakmead Village Court
Santa Clara, CA 95051

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